

UP04314

Silicon NPN epitaxial planar transistor (Tr1)
Silicon PNP epitaxial planar transistor (Tr2)

For switching

For digital circuit

■ Features

- Two elements incorporated into one package
(Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

■ Basic Part Number of Element

- UNR2214 (UN2214) + UNR2114 (UN2114)

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

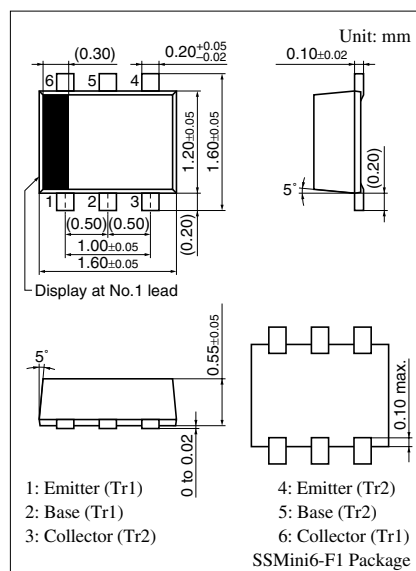
	Parameter	Symbol	Rating	Unit
Tr1	Collector to base voltage	V_{CBO}	50	V
	Collector to emitter voltage	V_{CEO}	50	V
	Collector current	I_{C}	100	mA
Tr2	Collector to base voltage	V_{CBO}	-50	V
	Collector to emitter voltage	V_{CEO}	-50	V
	Collector current	I_{C}	-100	mA
Overall	Total power dissipation	P_{T}	125	mW
	Junction temperature	T_{j}	125	$^\circ\text{C}$
	Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

- Tr1

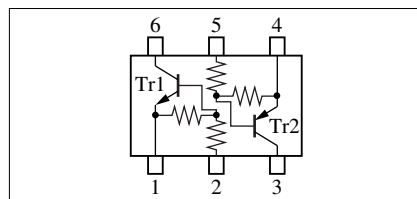
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector to base voltage	V_{CBO}	$I_{\text{C}} = 10 \mu\text{A}$, $I_{\text{E}} = 0$	50			V
Collector to emitter voltage	V_{CEO}	$I_{\text{C}} = 2 \text{ mA}$, $I_{\text{B}} = 0$	50			V
Collector cutoff current	I_{CBO}	$V_{\text{CB}} = 50 \text{ V}$, $I_{\text{E}} = 0$			0.1	μA
	I_{CEO}	$V_{\text{CE}} = 50 \text{ V}$, $I_{\text{B}} = 0$			0.5	
Emitter cutoff current	I_{EBO}	$V_{\text{EB}} = 6 \text{ V}$, $I_{\text{C}} = 0$			0.2	mA
Forward current transfer ratio	h_{FE}	$V_{\text{CE}} = 10 \text{ V}$, $I_{\text{C}} = 5 \text{ mA}$	80			
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_{\text{C}} = 10 \text{ mA}$, $I_{\text{B}} = 0.3 \text{ mA}$			0.25	V
High-level output voltage	V_{OH}	$V_{\text{CC}} = 5 \text{ V}$, $V_{\text{B}} = 0.5 \text{ V}$, $R_{\text{L}} = 1 \text{ k}\Omega$	4.9			V
Low-level output voltage	V_{OL}	$V_{\text{CC}} = 5 \text{ V}$, $V_{\text{B}} = 2.5 \text{ V}$, $R_{\text{L}} = 1 \text{ k}\Omega$			0.2	V
Input resistance	R_{I}		-30%	10	+30%	$\text{k}\Omega$
Resistance ratio	$R_{\text{I}}/R_{\text{2}}$		0.17	0.21	0.25	
Transition frequency	f_{T}	$V_{\text{CB}} = 10 \text{ V}$, $I_{\text{E}} = -2 \text{ mA}$, $f = 200 \text{ MHz}$		150		MHz

Note) The part number in the parenthesis shows conventional part number.



Marking Symbol: CA

Internal Connection

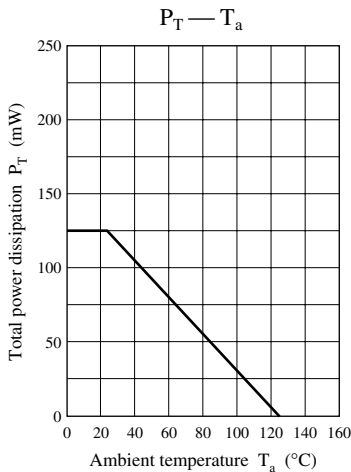


■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

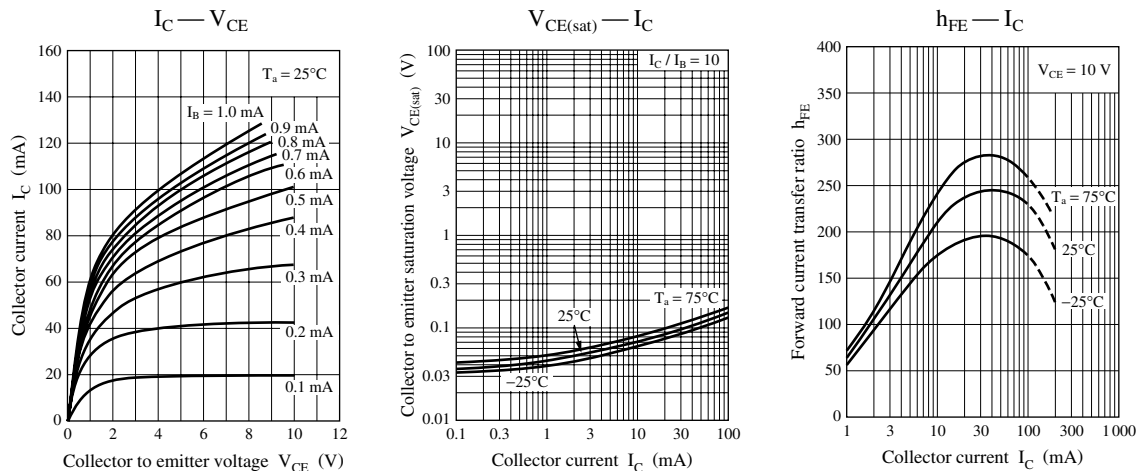
• Tr2

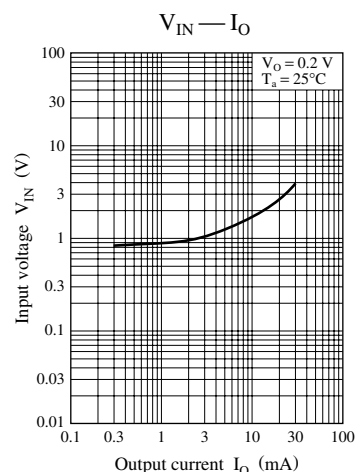
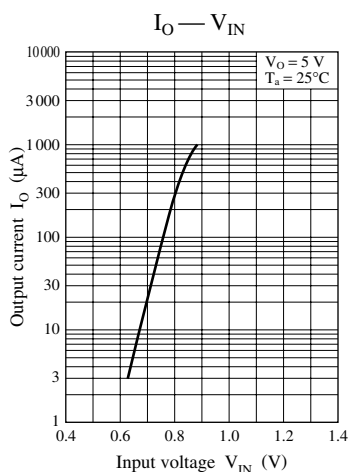
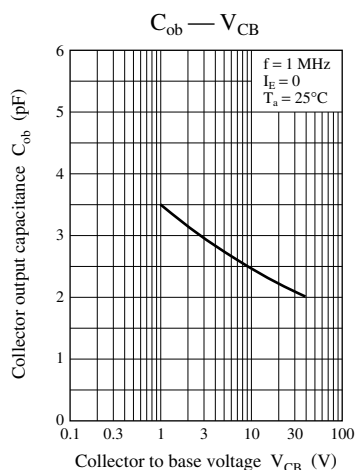
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector to base voltage	V_{CBO}	$I_{\text{C}} = -10\ \mu\text{A}$, $I_{\text{E}} = 0$	-50			V
Collector to emitter voltage	V_{CEO}	$I_{\text{C}} = -2\ \text{mA}$, $I_{\text{B}} = 0$	-50			V
Collector cutoff current	I_{CBO}	$V_{\text{CB}} = -50\ \text{V}$, $I_{\text{E}} = 0$			-0.1	μA
	I_{CEO}	$V_{\text{CE}} = -50\ \text{V}$, $I_{\text{B}} = 0$			-0.5	
Emitter cutoff current	I_{EBO}	$V_{\text{EB}} = -6\ \text{V}$, $I_{\text{C}} = 0$			-0.2	mA
Forward current transfer ratio	h_{FE}	$V_{\text{CE}} = -10\ \text{V}$, $I_{\text{C}} = -5\ \text{mA}$	80			
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_{\text{C}} = -10\ \text{mA}$, $I_{\text{B}} = -0.3\ \text{mA}$			-0.25	V
High-level output voltage	V_{OH}	$V_{\text{CC}} = -5\ \text{V}$, $V_{\text{B}} = -0.5\ \text{V}$, $R_{\text{L}} = 1\ \text{k}\Omega$	-4.9			V
Low-level output voltage	V_{OL}	$V_{\text{CC}} = -5\ \text{V}$, $V_{\text{B}} = -2.5\ \text{V}$, $R_{\text{L}} = 1\ \text{k}\Omega$			-0.2	V
Input resistance	R_{I}		-30%	10	+30%	$\text{k}\Omega$
Resistance ratio	$R_{\text{I}}/R_{\text{2}}$		0.17	0.21	0.25	
Transition frequency	f_{T}	$V_{\text{CB}} = -10\ \text{V}$, $I_{\text{E}} = 1\ \text{mA}$, $f = 200\ \text{MHz}$		80		MHz

Common characteristics chart

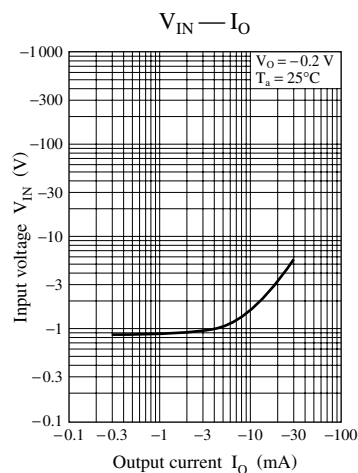
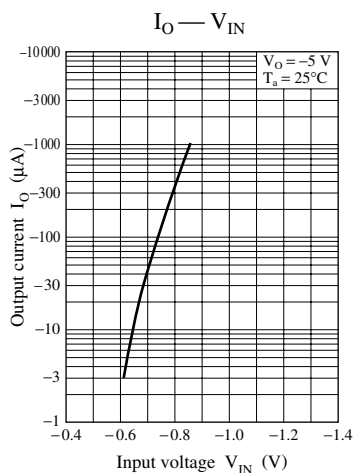
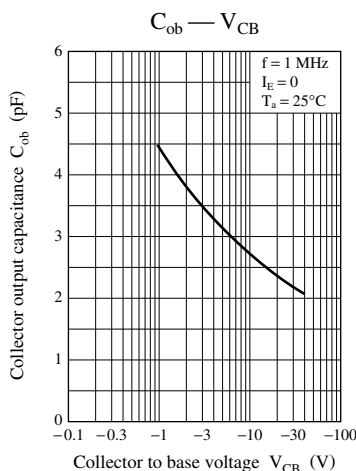
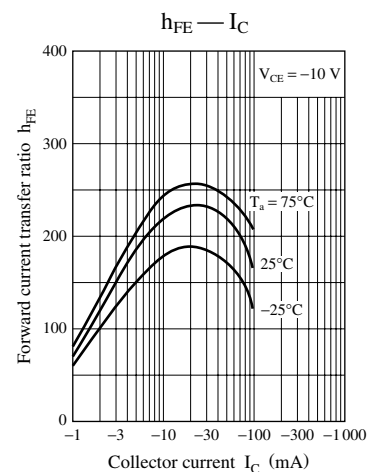
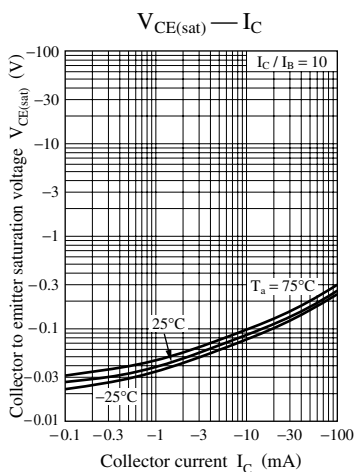
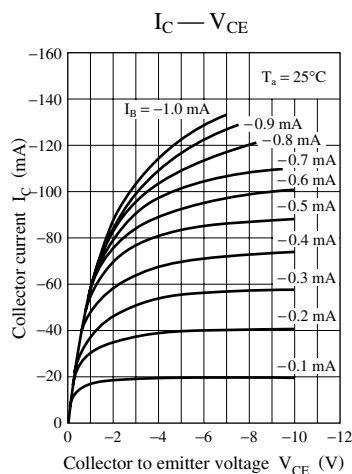


Characteristics chart of Tr1





Characteristics chart of Tr2



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